# UNISONIC TECHNOLOGIES CO., LTD

# **D44VH10**

## NPN SILICON TRANSISTOR

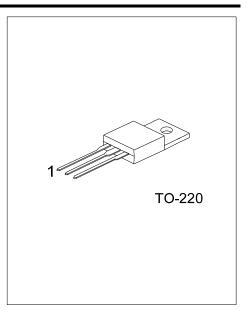
# NPN COMPLEMENTARY SILICON POWER **TRANSISTORS**

#### DESCRIPTION

The UTC D44VH10 is complementary silicon power transistors are designed for high-speed switching applications, such as switching regulators and high frequency inverters. The devices are also well-suited for drivers for high power switching circuits.



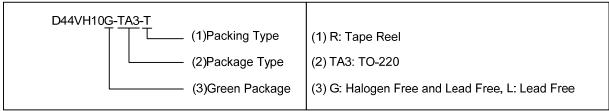
- \* Low Collector-Emitter Saturation Voltage: V<sub>CE(SAT)</sub>=0.4V (Max.) @ 8.0A
- \* Complementary Pairs Simplify Circuit Designs



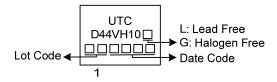
#### ORDERING INFORMATION

	Ordering Number		Daakana	Pin Assignment			Dealine
	Lead Free	Halogen Free	Package	1	2	3	Packing
Γ	D44VH10L-TA3-T	D44VH10G-TA3-T	TO-220	B	C	F	Tube

Note: Pin Assignment: B: Base E: Emitter C: Collector



#### **MARKING**



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## ■ ABSOLUTE MAXIMUM RATING (T<sub>A</sub>=25°C, unless otherwise specified)

PARAMETER		SYMBOL	RATINGS	UNIT
Collector-Base Voltage		V <sub>CBO</sub>	100	V
Collector-Emitter Voltage		V <sub>CEO</sub>	80	V
Emitter-Base Voltage		V <sub>EBO</sub>	7	V
Callantan Cumant	DC	lc	15	Α
Collector Current	Pulse(Note 2)	I <sub>CM</sub>	20	Α
Power Dissipation	T <sub>C</sub> =25°C	P <sub>D</sub>	83	W
Junction Temperature		$T_J$	-40 ~ +150	°C
Storage Temperature		T <sub>STG</sub>	-55 ~ +150	°C

Notes: 1. Absolute maximum ratings are those values beyond which the device could be permanently damaged.

Absolute maximum ratings are stress ratings only and functional device operation is not implied.

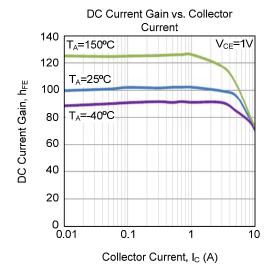
## ■ ELECTRICAL CHARACTERISTICS (T<sub>C</sub>=25°C, unless otherwise specified)

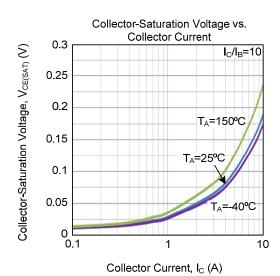
			_		_				
PARAMETER	SYMBOL	TEST CONDITIONS	MIN	TYP	MAX	UNIT			
OFF CHARACTERISTICS									
Collector-Emitter Sustaining Voltage	V <sub>CEO(SUS)</sub>	I <sub>C</sub> =25mA, I <sub>B</sub> =0	80			V			
Collector-Emitter Cutoff Current	Icev	V <sub>CE</sub> =Rated V <sub>CEV</sub> , V <sub>BE(OFF)</sub> =-4.0V			10	μΑ			
Emitter Cutoff Current	I <sub>EBO</sub>	V <sub>EB</sub> =7.0V, I <sub>C</sub> =0			10	μΑ			
ON CHARACTERISTICS(Note)									
DC Current Cain	h <sub>FE</sub>	V <sub>CE</sub> =1.0V, I <sub>C</sub> =2.0A	35						
DC Current Gain		V <sub>CE</sub> =1.0V, I <sub>C</sub> =4.0A	20						
Collector-Emitter Saturation Voltage	V <sub>CE(SAT)</sub>	I <sub>C</sub> =8.0A, I <sub>B</sub> =0.4A			0.4	V			
Base-Emitter Saturation Voltage	V <sub>BE(SAT)</sub>	I <sub>C</sub> =8.0A, I <sub>B</sub> =0.4A			1.5	V			
DYNAMIC CHARACTERISTICS									
Current Gain Bandwidth Product	f⊤			50		MHz			
Output Capacitance	Cob			120		рF			

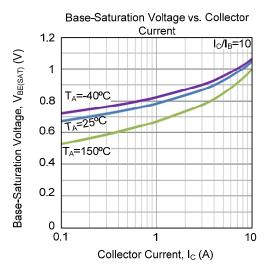
Note: Pulse test: Pulse Width  $\leq$  300  $\mu$ s, Duty Cycle  $\leq$  2%.

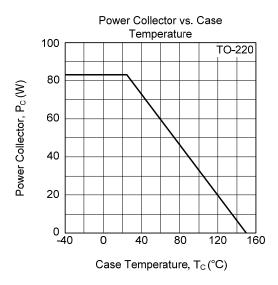
<sup>2.</sup> Pulse Width ≤ 6.0ms, Duty Cycle ≤ 50%.

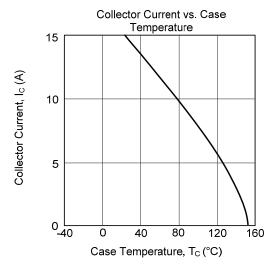
# ■ TYPICAL CHARACTERISTICS

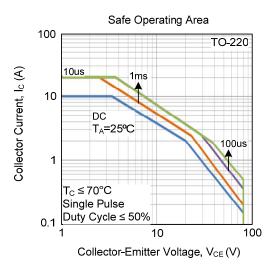












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